

Operation: 垫高卧式 (垫高 1.8mm) D+S 结构 & 3.1Type-C 连接器 (24PIN)



ITEM NO.: MC-313H-18 (Consumer Electronics)

(L11.1×W9.84×H 5.2mm & TYPE-C CONNECTORS)

3.1 Type-C CONNECTORS



Technical parameter

外焊贴片式 SMT

侧向导入 LATERAL

精密部品 NICETY

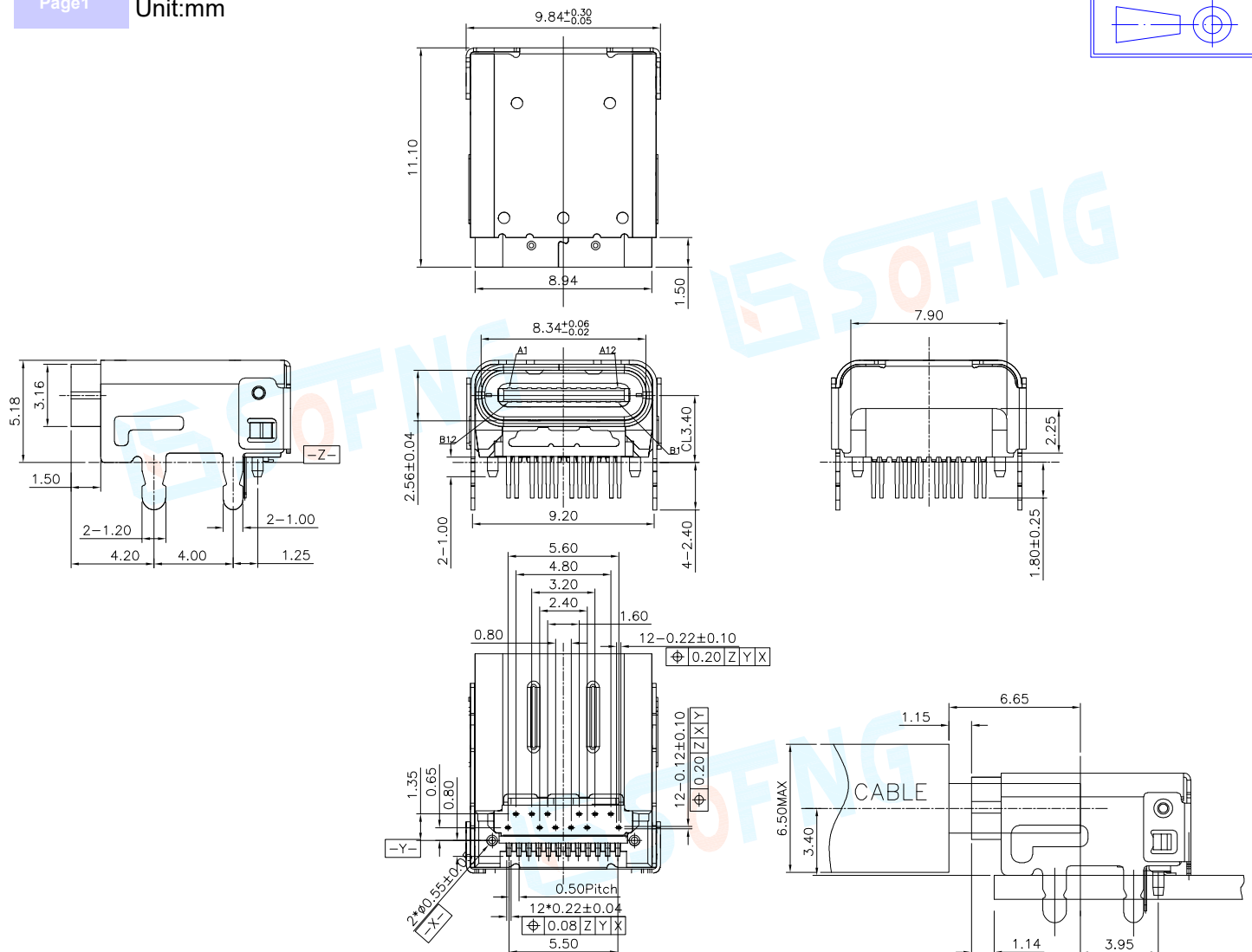
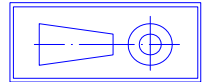
可靠 STABILIZE

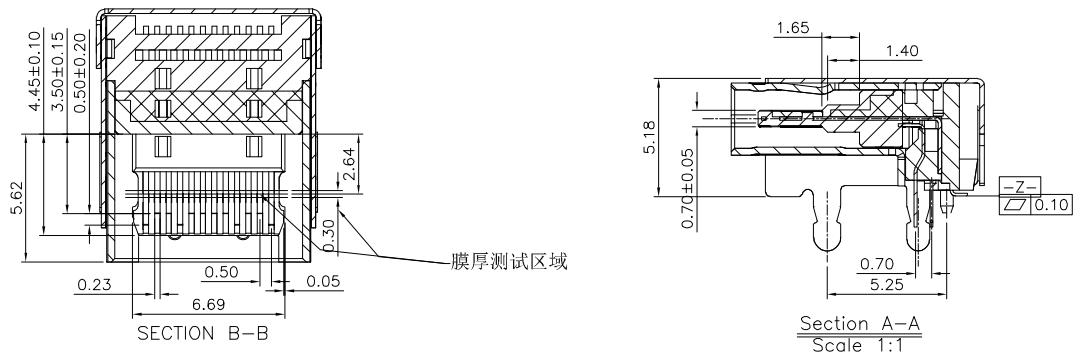
环保材质 RoHS

PROJECT		LEVEL	A[better product]	B[average product]
Electrical Properties	Contact Rating		5A, 24V DC	
	Initial Contact Resistance		30mΩ max.	50mΩ max.
	Insulation Resistance		100MΩ min.500V DC	Skey/PD: 100MΩ min.300V DC
	Withstand Voltage		500V AC for 1 minute	350 V AC for 1 minut
Durable Performance	There No Load		6,500 Cycles	5,500 Cycles
	Rated Load		5,500 Cycles	4,500 Cycles
	Storage Temp		25℃/50℃RH (Operating temperature: -35℃~+75℃)	

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Unit:mm





SPECIFIED TOLERANCES

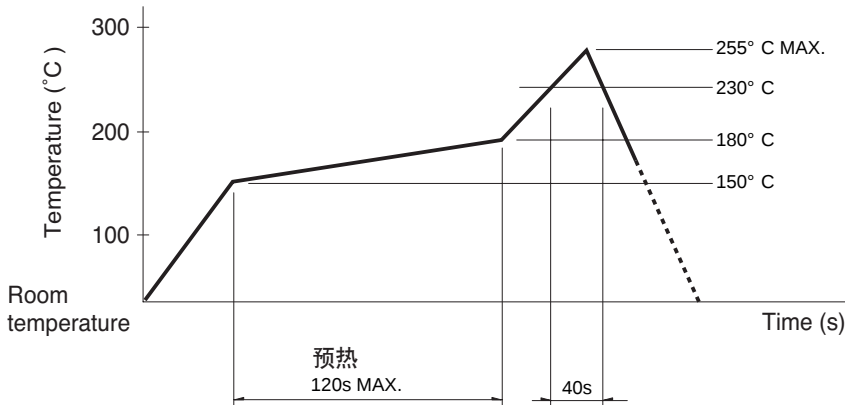
UNLESS OTHERWISE



DECIMALS	ANGLES
X.X :±0.25	X.X :±3°
X.XX :±0.15	X.XX :±2°
X.XXX :±0.10	

回流方式的参考举例

1. 加热方式远红外线加热的上下加热方式。
2. 温度测量方式用 V0.1 ~ V0.2 的 CA(K) 或 CC(T) 进行测量。
3. 温度分布



手焊接时

项 目	条 件
焊接温度	350℃ max.
连续焊接时间	3s max.
焊剂斗容量	60W max.

自动浸焊时

项 目	条 件
助焊剂附着量	不附着于零部件贴装面的程度
预热温度	印刷电路板焊接面的周围温度 100℃ max.
预热温度时间	60s max.
焊接温度	260℃ max.
焊接浸渍时间	5s max.
焊接次数	2次以下

Material declaration			
No.	NAME	MATERIAL	DESCRIPTION
① A	TERMINAL 接触端子	COPPER ALLOY 【G/F】	2.0 μ m Ni PLATED OVERALL; 0.25 μ m Au PLATED CONTACT AREA; GOLD FLASH ON SOLDER AREA.
② B	HOUSING 基座	THERMOPLASTIC	UL 94V-0,COLOR:BLACK;
③ C	SHIELDING PLATE 屏蔽壳	STAINLESS STEE	【G/F】 0.25 μ m Ni PLATED OVERALL;
④ D	SHELL 外壳	STAINLESS STEE	【G/F】 0.25 μ m Ni PLATED OVERALL;
⑤ E	GND RING 接地件	STAINLESS STEE	STAINLESS STEEL;

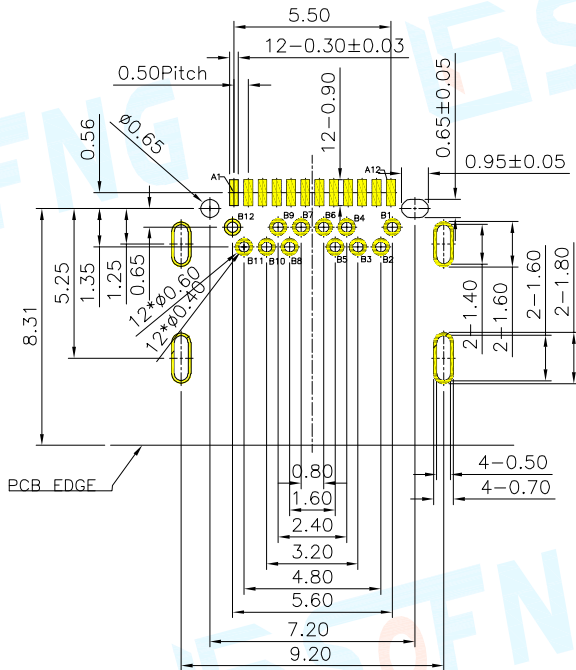
PRODUCT MEET THE REQUEST OF THE ROHS

MATTER	RoHs (PPM)
Cd	≦ 100
Pb	≦ 1000
Hg	≦ 1000
Cr6+	≦ 1000
PBB	≦ 1000
PBDE	≦ 1000



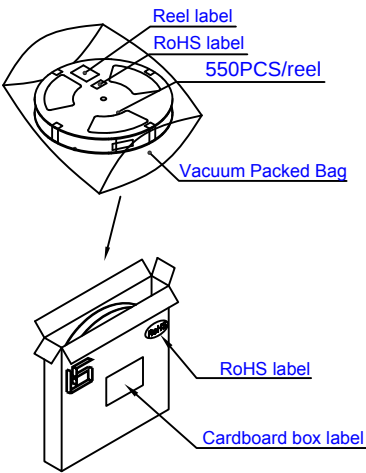
MATERIAL

Operating Force	Inward	8.0~20.0N. (1N.=100gram-force)	Solder-ability (Max.)	
	Exiting	8.0~20.0N. (1N.=100gram-force)	IR Reflow:255°C, 5sec.	Manual:350°C, 3sec.



推荐锡膏厚度	0.12mm
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PIN ASSIGNMENTS



PIN	Signal NAME	Description	PIN	Signal NAME	Description
A 1	GND	Ground return	B12	GND	Ground return
A 2	SSTXp1	Positive half of first SuperSpeed TX differential pair	B11	SSRXp1	Positive half of second SuperSpeed RX differential pair
A 3	SSTXn1	Negative half of first SuperSpeed TX differential pair	B10	SSRXn1	Negative half of second SuperSpeed RX differential pair
A 4	V BUS	Bus Power	B 9	V BUS	Bus Power
A 5	CC1	Configuration Channel	B 8	SBU2	Sideband Use (SBU)
A 6	Dp1	Positive half of the USB 2.0 differential pair-Position 1	B 7	Dn2	Negative half of the USB 2.0 differential pair-Position 2
A 7	Dn1	Negative half of the USB 2.0 differential pair-Position 1	B 6	Dp2	Positive half of the USB 2.0 differential pair-Position 2
A 8	SBU1	Sideband Use (SBU)	B 5	CC2	Configuration Channel
A 9	V BUS	Bus Power	B 4	V BUS	Bus Power
A10	SSRXn2	Negative half of second SuperSpeed RX differential pair	B 3	SSTXn2	Negative half of first SuperSpeed TX differential pair2
A11	SSRXp2	Positive half of second SuperSpeed RX differential pair	B 2	SSTXp2	Positive half of first SuperSpeed TX differential pair2
A12	GND	Ground return	B 1	GND	Ground return

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